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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/799,292	03/12/2004	Kyoung-woo Lee	SAM-0560	8218
Steven M. Mill	7590 01/05/200 S	7	EXAMINER	
MILLS & ONELLO LLP SARKAR, ASOK K				
Suite 605 Eleven Beacon	Street		ART UNIT	PAPER NUMBER
Boston, MA 02	108		2891	
SHORTENED STATUTORY PERIOD OF RESPONSE		MAIL DATE	DELIVERY MODE	
3 MONTHS		01/05/2007	PAPER	

Please find below and/or attached an Office communication concerning this application or proceeding.

If NO period for reply is specified above, the maximum statutory period will apply and will expire 6 MONTHS from the mailing date of this communication.

		Application No.	Applicant(s)			
		10/799,292	LEE ET AL.			
C	ffice Action Summary	Examiner	Art Unit			
		Asok K. Sarkar	2891			
	MAILING DATE of this communication app	ears on the cover sheet with the c				
Period for Re	•					
WHICHEV - Extensions of after SIX (6) - If NO period - Failure to re Any reply re	ENED STATUTORY PERIOD FOR REPLY ER IS LONGER, FROM THE MAILING DARFORM THE MAILING DARFORM THE MAILING DARFORM THE MEDITION TO THE MAILING DARFORM THE MEDITION T	ATE OF THIS COMMUNICATION 36(a). In no event, however, may a reply be tim vill apply and will expire SIX (6) MONTHS from a cause the application to become ABANDONE	N. nely filed the mailing date of this communication. D (35 U.S.C. § 133).			
Status	•					
1)⊠ Resi	oonsive to communication(s) filed on <u>30 No</u>	ovember 2006.				
· ·	This action is <b>FINAL</b> . 2b) ☐ This action is non-final.					
′ <del></del>	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is					
close	ed in accordance with the practice under E	x parte Quayle, 1935 C.D. 11, 45	63 O.G. 213.			
Disposition of	f Claims					
<u> </u>	n(s) <u>16-39</u> is/are pending in the application	1.				
-	4a) Of the above claim(s) is/are withdrawn from consideration.					
	n(s) <u>34-36</u> is/are allowed.					
	n(s) <u>16,22,27,30,31 and 37-39</u> is/are rejec	ted.				
· <u> </u>	n(s) <u>17-21,23-26,28,29,32 and 33</u> is/are ol					
8) Clair	n(s) are subject to restriction and/or	r election requirement.				
Application P	apers					
	specification is objected to by the Examine	r				
•	frawing(s) filed on is/are: a) ☐ acce		Examiner			
•	cant may not request that any objection to the					
	acement drawing sheet(s) including the correct					
•	path or declaration is objected to by the Ex	• • • • • • • • • • • • • • • • • • • •				
Priority under	35 U.S.C. § 119					
	owledgment is made of a claim for foreign	priority under 25 LLS C S 110(a)	. (d) or (f)			
	b) Some * c) None of:	priority under 35 U.S.C. § 119(a)	-(u) or (i).			
۳/⊔/۱. 1.□	Certified copies of the priority documents	s have been received				
	Certified copies of the priority documents		on No.			
	Copies of the certified copies of the prior					
	application from the International Bureau	•				
* See th	e attached detailed Office action for a list		ed.			
Attachment(s)						
	eferences Cited (PTO-892) raftsperson's Patent Drawing Review (PTO-948)	4) Interview Summary Paper No(s)/Mail Da				
	Disclosure Statement(s) (PTO/SB/08)	5) 🔲 Notice of Informal P				
	/Mail Date	6) Other:				

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#### **DETAILED ACTION**

## Response to Arguments

1. Applicant's arguments with respect to claims 16 – 39 have been considered but are most in view of the new ground(s) of rejection.

### Claim Rejections - 35 USC § 102

2. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (e) the invention was described in (1) an application for patent, published under section 122(b), by another filed in the United States before the invention by the applicant for patent or (2) a patent granted on an application for patent by another filed in the United States before the invention by the applicant for patent, except that an international application filed under the treaty defined in section 351(a) shall have the effects for purposes of this subsection of an application filed in the United States only if the international application designated the United States and was published under Article 21(2) of such treaty in the English language.
- 3. Claims 16, 22, 27, 30 and 31 are rejected under 35 U.S.C. 102(e) as being anticipated by Yoshitomi, US 6,740,974.

Regarding claim 16, Yoshitomi teaches a dual damascene interconnection structure with a metal – insulator – metal capacitor, the structure comprising:

- a via level intermetal dielectric 21 and a trench level intermetal dielectric 22
   which are sequentially stacked on a substrate;
- a dual damascene interconnection 27C formed in the via level intermetal
  dielectric and the trench level intermetal dielectric including a line trench
  extending through the trench level intermetal dielectric to the via level
  intermetal dielectric; and

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a metal – insulator – metal capacitor 20 formed between the via – level
intermetal dielectric and the trench – level intermetal dielectric to include a lower
electrode 16, a dielectric layer 17, and an upper electrode 18, the dual
damascene interconnection being substantially electrically isolated from the
metal-insulator-metal capacitor; and

 an upper metal interconnection 27b formed on and connected to the upper electrode with reference to Figs. 7 and 13 and corresponding text under columns 2 – 6.

Regarding claim 22, Yoshitomi teaches the upper electrode 18 is patterned to have a smaller area than that of each of the lower electrode 16 and the capacitor dielectric layer 17 with reference to Figs 7 and 13.

Regarding claim 27, Yoshitomi teaches a dual damascene interconnection is formed with Cu in column 4, lines 5-7.

Regarding claim 30, Yoshitomi teaches the dual damascene interconnection further includes a via hole formed in the via – level intermetal dielectric 21 with reference to Fig. 6.

Regarding claim 31, Yoshitomi teaches an upper metal interconnection positioned in a trench, wherein the trench is formed in the trench – level intermetal dielectric 22 to expose the upper electrode with reference to Figs 7 and 13.

4. Claims 37 – 39 are rejected under 35 U.S.C. 102(e) as being anticipated by Ogawa, US 2003/0012117.

Regarding claim 37, Ogawa teaches a dual damascene interconnection

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structure with a metal – insulator – metal capacitor, the structure comprising:

a via – level intermetal dielectric 22 and a trench – level intermetal dielectric
 41which are sequentially stacked on a substrate 10;

- a dual damascene interconnection 42/30C formed in the via level intermetal dielectric and the trench – level intermetal dielectric;
- a metal insulator metal MC capacitor formed between the via level intermetal dielectric and the trench – level intermetal dielectric to include a lower electrode 33b, a dielectric layer 34, and an upper electrode 35; and
- a first lower metal interconnection 21b formed between the substrate and the via
   level intermetal dielectric, herein the lower electrode 33b is directly connected
   to the first lower metal interconnection 21b with reference to Fig.1A.

Regarding claim 38, Ogawa teaches a via 30b formed in the via – level intermetal dielectric 22, wherein the lower electrode 33b is located on the via with reference to Fig. 1A.

Regarding claim 39, Ogawa teaches the via and the lower electrode are united together as a single body with reference to Fig. 1A.

## Allowable Subject Matter

- 5. Claims 17 21,23 26, 28, 29, 32 and 33 objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims.
- 6. Claims 34 36 are allowed.

#### Conclusion

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7. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

8. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Asok K. Sarkar whose telephone number is 571 272 1970. The examiner can normally be reached on Monday - Friday (8 AM- 5 PM).

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, William B. Baumeister can be reached on 571 272 1722. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

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9. Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

Asok K. Sarkar

December 21, 2006

**Primary Examiner**